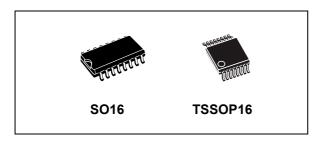


8-bit shift register with output latches (3-state)

Datasheet - production data



Features

- High speed: f_{MAX} = 59 MHz (typ.) at V_{CC} = 6 V
- Low power dissipation: I_{CC} = 4 μA (max.) at T_A= 25 °C
- High noise immunity:
 V_{NIH} = V_{NIL} = 28% V_{CC} (min.)
- Symmetrical output impedance:
 - $|I_{OH}| = I_{OL} = 6$ mA (min.) for QA to QH
 - $|I_{OH}| = I_{OL} = 4 \text{ mA (min.) for QH'}$
- Balanced propagation delays: t_{Pl H} ≅ t_{PHI}
- Wide operating voltage range:
 V_{CC} (opr.) = 2 V to 6 V
- Pin and function compatible with 74 series 595
- ESD performance

HBM: 2 kVMM: 200 VCDM: 1 kV

Applications

- Automotive
- Industrial
- Computer
- Consumer

Description

The M74HC595 device is a high speed CMOS 8-bit shift register with output latches (3-state) fabricated with silicon gate C²MOS technology.

This device contains an 8-bit serial in, parallel out shift register that feeds an 8-bit D-type storage register. The storage register has 8 3-state outputs. Separate clocks are provided for both the shift register and the storage register.

The shift register has direct overriding clear, serial input, and serial output (standard) pins for cascading. Both the shift register and storage register use positive edge triggered clocks. If both clocks are connected together, the shift register state will always be one clock pulse ahead of the storage register.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

Table 1. Device summary

Order code	Temperature range	Package	Packing	Marking
M74HC595RM13TR	-55/+125 °C	SO16		74HC595
M74HC595YRM13TR ⁽¹⁾	-40/+125 °C	SO16 (automotive grade)	Tano and roal	74HC595Y
M74HC595TTR	-55/+125 °C	TSSOP16	Tape and reel	HC595
M74HC595YTTR ⁽¹⁾	-40/+125 °C	TSSOP16 (automotive grade)		HC595Y

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

Contents M74HC595

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2	Functional description4
3	Electrical characteristics
4	Package information
	4.1 SO16 package information
	4.2 TSSOP16 package information
5	Ordering information
6	Revision history

M74HC595 Pin information

Pin information

G (13) EN3 RCK (12) 16 V_CC QB 1 SCLR (10) R SRG8 QA QC 2 SCK SI (15) QA QD 3 2D (1) QB G QE 4 (2) QC RCK QF 5 (3) QD (4)_ QE SCK QG 6 (5) QF SCLR QH (6) QG QH' ⁽⁷⁾ QH GND 2D ⊳ 3⊽ (9) QH' AM03212 AM03213

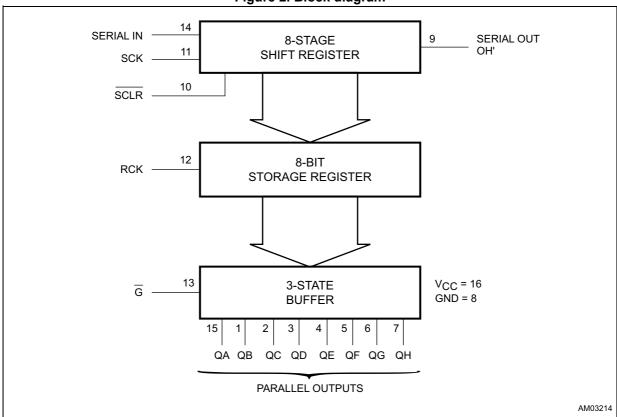
Figure 1. Pin connection and IEC logic symbols

Table 2. Pin description

Pin no	Symbol	Name and function							
1, 2, 3, 4, 5, 6, 7, 15	QA to QH	Data outputs							
9	QH'	Serial data outputs							
10	SCLR	Shift register clear input							
11	SCK	Shift register clock input							
13	ĪG	Output enable input							
14	SI	Serial data input							
12	RCK	Storage register clock input							
8	GND	Ground (0 V)							
16	V _{CC}	Positive supply voltage							

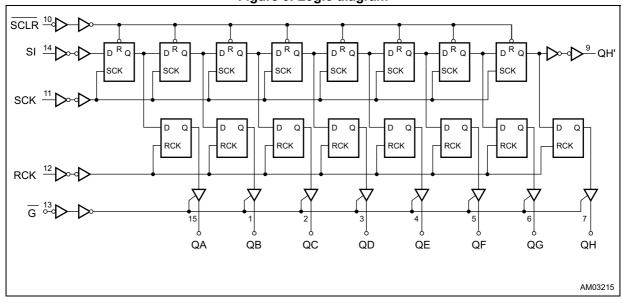
2 Functional description

Figure 2. Block diagram



1. This block diagram has not be used to estimate propagation delays.

Figure 3. Logic diagram



1. This logic diagram has not be used to estimate propagation delays.

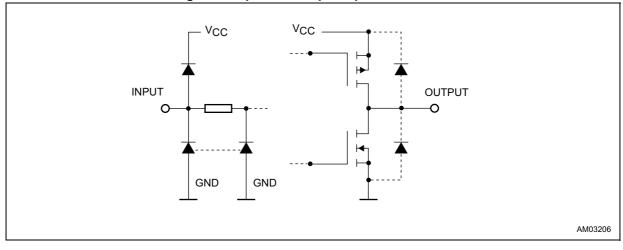
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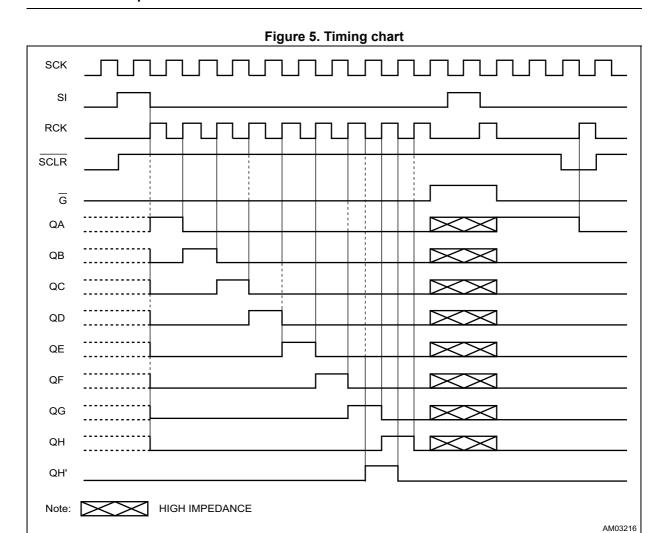
Table 3. Truth table⁽¹⁾

		Inputs			Quita vita
SI	scĸ	SCLR	RCK	G	- Outputs
Х	Х	X	Х	Н	QA through QH outputs disable
Х	Х	Х	Х	L	QA through QH outputs enable
Х	Х	L	Х	Х	Shift register is cleared
L		Н	Х	Х	First stage of S.R. becomes "L" other stages store the data of previous stage, respectively
Н		Н	Х	Х	First stage of S.R. becomes "H" other stages store the data of previous stage, respectively
Х	Z	Н	Х	Х	State of S.R. is not changed
Х	Х	Х	丁	Х	S.R. data is stored into storage register
Х	Х	Х	Z	Х	Storage register state is not changed

^{1.} X: don't care.

Figure 4. Input and output equivalent circuit





3 Electrical characteristics

Table 4. Absolute maximum ratings⁽¹⁾

Symbol	Parameter	Parameter			
V _{CC}	Supply voltage		-0.5 to +7		
V _I	DC input voltage		0.5 to \/ 0.5	V	
V _O	DC output voltage		-0.5 to V _{CC} + 0.5		
I _{IK}	DC input diode current		120		
I _{OK}	DC output diode current	±20	mA		
Io	DC output current	DC output current			
I _{CC} or I _{GND}	DC V _{CC} or ground current		±70		
П	Dower discination	SOP	500 ⁽²⁾	m\\/	
P_{D}	Power dissipation	450 ⁽²⁾	mW		
T _{stg}	Storage temperature	-65 to +150	°C		
T _L	Lead temperature (10 sec.)	300	7		

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 5. Recommended operating conditions

Symbol	Parameter	Parameter					
V _{CC}	Supply voltage		2 to 6				
VI	Input voltage		O to V	V			
V _O	Output voltage	0 to V _{CC}					
T _{op}	Operating temperature		-55 to 125	°C			
		V _{CC} = 2.0 V	0 to 1000				
t _r , t _f	Input rise and fall time	V _{CC} = 4.5 V	0 to 500	ns			
		V _{CC} = 6.0 V	0 to 400				

^{2.} Power dissipation at 65 °C. Derating from 65 °C to 125 °C: SO package -7 mW/°C; TSSOP package -6.1 mW/°C.

Table 6. DC specifications

		Те	st condition	Value							
Symbol	Parameter			T,	_A = 25 °	°C	-40 to	85 °C	-55 to	125 °C	Unit
		V _{CC} (V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0		1.5			1.5		1.5		
V_{IH}	High level input voltage	4.5		3.15			3.15		3.15		V
		6.0		4.2			4.2		4.2		
		2.0				0.5		0.5		0.5	
V_{IL}	Low level input voltage	4.5				1.35		1.35		1.35	V
	3	6.0				1.8		1.8		1.8	
		2.0	I _O = -20 μA	1.9	2.0		1.9		1.9		
	High level output	4.5	I _O = -20 μA	4.4	4.5		4.4		4.4		
V_{OH}	voltage	6.0	I _O = -20 μA	5.9	6.0		5.9		5.9		٧
	(for QH' outputs)	4.5	I _O = -4.0 mA	4.18	4.31		4.13		4.10		
		6.0	I _O = -7.8 mA	5.68	5.8		5.63		5.60		
		2.0	I _O = -20 μA	1.9	2.0		1.9		1.9		
	High level output	4.5	I _O = -20 μA	4.4	4.5		4.4		4.4		
V_{OH}	voltage (for QA to QH	6.0	I _O = -20 μA	5.9	6.0		5.9		5.9		V
	outputs)	4.5	I _O = -6.0 mA	4.18	4.31		4.13		4.10		
		6.0	I _O = -7.8 mA	5.68	5.8		5.63		5.60		
		2.0	I _O = 20 μA		0.0	0.1		0.1		0.1	
	Low level output	4.5	I _O = 20 μA		0.0	0.1		0.1		0.1	
V_{OL}	voltage	6.0	I _O = 20 μA		0.0	0.1		0.1		0.1	٧
	(for QH' outputs)	4.5	I _O = 4.0 mA		0.17	0.26		0.33		0.40	
		6.0	I _O = 7.8 mA		0.18	0.26		0.33		0.40	
		2.0	I _O = 20 μA		0.0	0.1		0.1		0.1	
	Low level output	4.5	I _O = 20 μA		0.0	0.1		0.1		0.1	
V_{OL}	voltage (for QA to QH	6.0	I _O = 20 μA		0.0	0.1		0.1		0.1	٧
	outputs)	4.5	I _O = 6.0 mA		0.17	0.26		0.33		0.40	
		6.0	I _O = 7.8 mA		0.18	0.26		0.33		0.40	
I _I	Input leakage current	6.0	V _I = V _{CC} or GND			±0.1		±1		±1	μΑ
I _{OZ}	High impedance output leakage current	6.0	$V_I = V_{IH} \text{ or } V_{IL}$ $V_O = V_{CC} \text{ or GND}$			±0.5		±5		±10	μΑ
I _{CC}	Quiescent supply current	6.0	V _I = V _{CC} or GND			4		40		80	μΑ

Table 7. AC electrical characteristics (C_L = 50 pF, input t_r = t_f = 6 ns)

		Te	est condi	tion) (<u>-</u>		<u> </u>	Value		,		
Symbol	Parameter	V 00	0 (-5)		T,	_A = 25°	C	-40 to	85°C	-55 to	125°C	Unit
		V _{CC} (V)	C _L (pF)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
	Output	2.0				25	60		75		90	
t _{TLH} , t _{THL}	transition time	4.5	50			7	12		15		18	ns
	(Qn)	6.0				6	10		13		15	
	Output	2.0				30	75		95		115	
t_{TLH} , t_{THL}	transition time	4.5	50			8	15		19		23	ns
	(QH')	6.0				7	13		16		20	
	Propagation	2.0				45	125		155		190	
t_{PLH}, t_{PHL}	delay time	4.5	50			15	25		31		38	ns
	(SCK - QH')	6.0				13	21		26		32	
	Propagation	2.0				60	175		220		265	
t _{PLH} , t _{PHL}	delay time	4.5	50			18	35		44		53	ns
	(SCLR - QH')	6.0					15	30		37		45
		2.0				60	150		190		225	
	Propagation	4.5	50			20	30		38		45	ns
t _{PLH} , t _{PHL}	delay time	6.0				17	26		32		38	
	(RCK - Qn)	2.0				75	190		240		285	
		4.5	150			25	38		48		57	ns
		6.0				22	32		41		48	
		2.0				45	135		170		205	
	I II and	4.5	50	$R_L = 1 K\Omega$		15	27		34		41	ns
	High impedance	6.0				13	23		29		35	
t_{PZL}, t_{PZH}	output enable time	2.0				60	175		220		265	
	ume	4.5	150	$R_L = 1 K\Omega$		20	35		44		53	ns
		6.0				17	30		37		45	
	High	2.0				30	150		190		225	
t _{PLZ} , t _{PHZ}	impedance output disable	4.5	50	R _L = 1 KΩ		15	30		38		45	ns
	time	6.0				14	26		32		38	

Table 7. AC electrical characteristics (C_L = 50 pF, input t_r = t_f = 6 ns) (continued)

		Te	est condit	ion				Value)			
Symbol	Parameter		a (=)		T	_A = 25°	С	-40 to	85°C	-55 to	125°C	Unit
		V _{CC} (V)	C _L (pF)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0			6.0	17		4.8		4		
		4.5	50		30	50		24		20		MHz
f	Maximum clock	6.0			35	59		28		24		
f _{MAX}	frequency	2.0			5.2	14		4.2		3.4		
		4.5	150		26	40		21		17		MHz
		6.0			31	45		25		20		
	Minimum pulse	2.0				17	75		95		110	
$t_{W(H)}$	width	4.5	50			6	15		19		22	ns
	(SCK, RCK)	6.0				6	13		16		19	
	Minimum pulse	2.0				20	75		95		110	
$t_{W(L)}$	width	4.5	50			6	15		19		22	ns
	(SCLR)	6.0				6	13		16		19	
	Minimum setup	2.0				25	50		65		75	
t_s	time	4.5	50			5	10		13		15	ns
	(SI - CCK)	6.0				4	9		11		13	
	Minimum setup	2.0				35	75		95		110	
t _s	time	4.5	50			8	15		19		22	ns
	(SCK - RCK)	6.0				6	13		16		19	
	Minimum setup	2.0				40	100		125		145	
t _s	time	4.5	50			10	20		25		29	ns
	(SCRL - RCK)	6.0				7	17		21		25	
		2.0					0		0		0	
t _h	Minimum hold time	4.5	50				0		0		0	ns
		6.0					0		0		0	
		2.0				15	50		65		75	
t _{REM}	Minimum clear removal time	4.5	50			3	10		13		15	ns
		6.0				3	9		11		13	

		Test condition	st condition Value								
Symbol	Parameter	V 00	Ţ	_A = 25 °	С	-40 to	85 °C	-55 to	125 °C	Unit	
		V _{CC} (V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.		
C _{IN}	Input capacitance			5	10		10		10		
C _{PD}	Power dissipation capacitance ⁽¹⁾			184						pF	

 C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to *Figure 6: Test circuit*t). Average operating current can be obtained by the following equation: $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$.

Figure 6. Test circuit

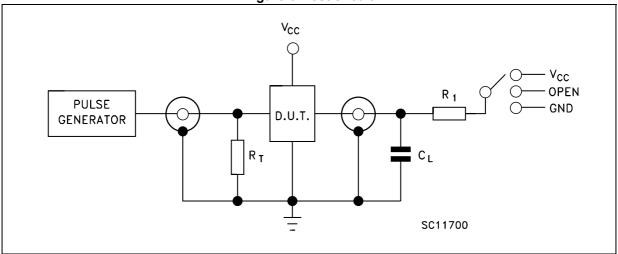


Table 9. Propagation delay time configuration

Test	Switch
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	V _{CC}
t _{PZH} , t _{PHZ}	GND

 C_L = 50 pF/150 pF or equivalent (includes jig and probe capacitance) R_1 = 1 K Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω). Note:

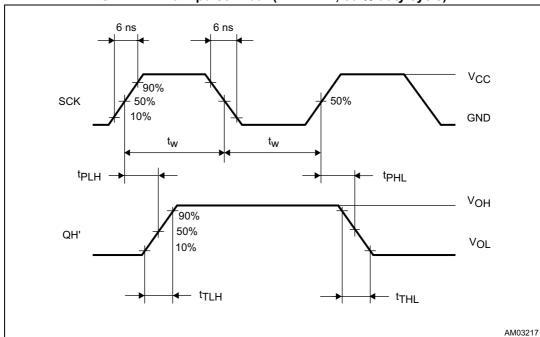
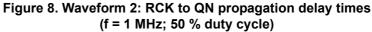
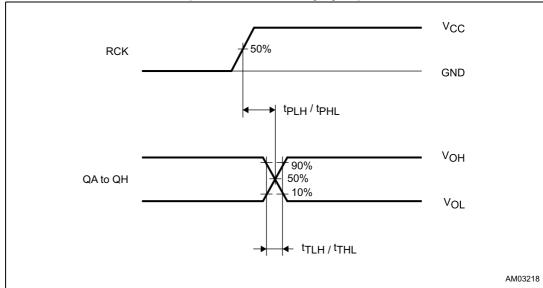


Figure 7. Waveform 1: SCK to QH' propagation delay times, SCK minimum pulse width (f = 1 MHz; 50 % duty cycle)

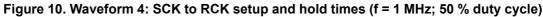


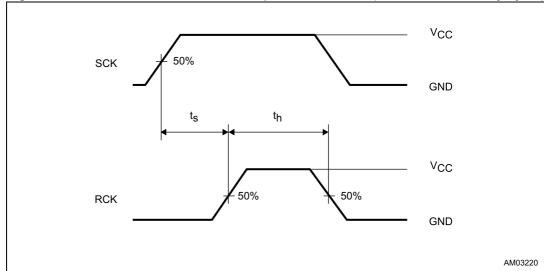


SI 50% 50% GND VCC
SCK GND

AM03219

Figure 9. Waveform 3: SI to SCK setup and hold times (f = 1 MHz; 50 % duty cycle)





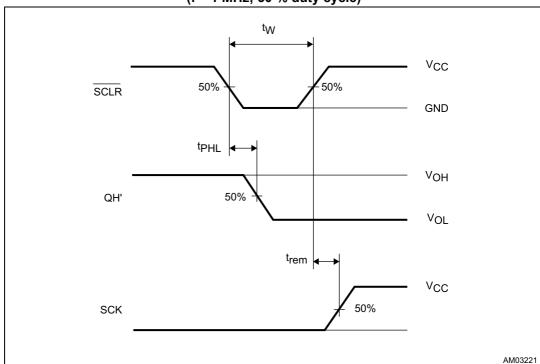
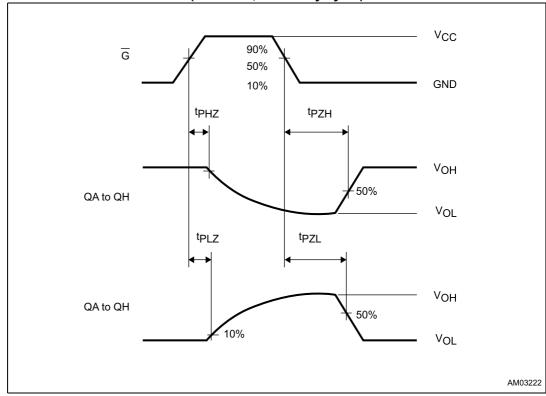


Figure 11. Waveform 5: SCLR minimum pulse width, minimum removal time (f = 1 MHz; 50 % duty cycle)





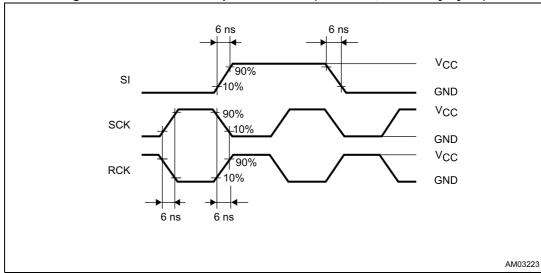


Figure 13. Waveform 7: input waveform (f = 1 MHz; 50 % duty cycle)



Package information M74HC595

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



M74HC595 Package information

4.1 SO16 package information

Figure 14. SO16 package outline

Table 10. SO16 package mechanical data

	Dimensions						
Symbol		mm			inch		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.75			0.068	
a1	0.1		0.2	0.004		0.008	
a2			1.65			0.064	
b	0.35		0.46	0.013		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.019		
c1			45°	(typ.)			
D	9.8		10	0.385		0.393	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		8.89			0.350		
F	3.8		4.0	0.149		0.157	
G	4.6		5.3	0.181		0.208	
L	0.5		1.27	0.019		0.050	
М			0.62			0.024	
S	8° (max.)						

Package information M74HC595

A PO SO-16-TR

Figure 15. SO16 tape and reel information

1. Drawing is not in scale.

Table 11. SO16 tape and reel information

	Dimensions						
Symbol		mm			inch		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			22.4			0.882	
Ao	6.45		6.65	0.254		0.262	
Во	10.3		10.5	0.406		0.414	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	

M74HC595 Package information

4.2 TSSOP16 package information

Figure 16. TSSOP16 package outline

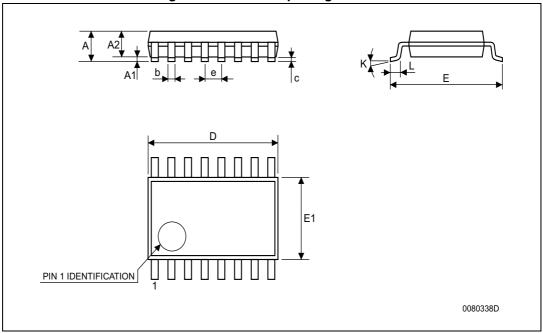


Table 12. TSSOP16 package mechanical data

	Dimensions					
Symbol		mm			inch	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.0079
D	4.9	5 5	.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
е		0.65			0.0256	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

Package information M74HC595

A PO TSSOP16-TR

Figure 17. TSSOP16 tape and reel information

1. Drawing is not in scale.

Table 13. TSSOP16 tape and reel information

Symbol	Dimensions						
		mm			inch		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			22.4			0.882	
Ao	6.7		6.9	0.264		0.272	
Во	5.3		5.5	0.209		0.217	
Ko	1.6		1.8	0.063		0.071	
Ро	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	

5 Ordering information

Table 14. Device summary

Order code	Temp. range	Package	Packing	Marking
M74HC595RM13TR	-55/+125 °C	SO16		74HC595
M74HC595YRM13TR ⁽¹⁾	-40/+125 °C	SO16 (automotivegrade)	Tape and reel	74HC595Y
M74HC595TTR	-55/+125 °C	TSSOP16	rape and reer	HC595
M74HC595YTTR ⁽¹⁾	-40/+125 °C	TSSOP16 (automotive grade)		HC595Y

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

6 Revision history

Table 15. Document revision history

Date	Revision	Changes
18-Apr-2013	5	Added Applications to page 1. Updated Table 1 (updated data, removed M74HC595M1R order code, added M74HC595RM13TR, M74HC595YRM13TR, M74HC595TTR, and M74HC595YTTR order code, temperature range, marking, updated package and packaging). Redrawn Figure 1 to Figure 4 and Figure 7 to Figure 13. Moved Figure 1 to page 3. Added Contents. Added titles to Section 1 to Section 6 (reformatted Section 1 and Section 2). Added title to Table 9. Added cross-reference to note 1. below Table 8. Added ECOPACK text to Section 4, reformatted Section 4 (reversed order of figures and tables, added titles to Figure 14 to Figure 17 and Table 10 to Table 13, moved notes below Figure 15 and Figure 17). Added Table 15. Minor corrections throughout document.
10-Jan-2014	6	Removed PDIP16 package Added ESD data to Features Table 1: Device summary: updated footnote 1 Added Section 5: Ordering information Updated layout

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